Signatures of dynamically polarized nuclear spins in all-electrical lateral spin transport devices

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The effect of nuclear spins in Fe/GaAs all-electrical spin-injection devices is investigated. At temperatures below 50 K, strong modifications of the nonlocal spin signal are found that are characteristic for hyperfine coupling between conduction electrons and dynamically polarized nuclear spins. The perpendicular component of the nuclear Overhauser field depolarizes electron spins near zero in-plane external magnetic field, and can suppress such dephasing when antialigned with the external field, leading to satellite peaks in a Hanle measurement. The features observed agree well with a Monte Carlo simulation of the spin-diffusion equation including hyperfine interaction and are used to study the nuclear-spin dynamics and to quantify the Overhauser field that is related to the spin polarization of the injected electrons.

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The interdependence of nuclear- and electron-spin dynamics in semiconductors caused by the contact hyperfine interaction leads to a rich variety of phenomena that significantly alter the behavior of independent electron and nuclear systems. For instance, fully polarized nuclear spins in GaAs create an effective magnetic field of 5.3 T acting on the spin of conductance-band electrons. This interaction has implications for applications in quantum information processing and spintronics. On the one hand it can be employed as a means to efficiently control the electron-spin state¹ but on the other hand it also leads to spin dephasing. Conduction-band electron spins in a semiconductor can be efficiently polarized either by means of optical orientation² or spin injection from ferromagnetic contacts.³⁻⁶ The hyperfine interaction leads to a flip-flop spin scattering between the electron and nuclear spins that dynamically transfers the spin polarization to the nuclear system.^{7,8} The static part of the hyperfine interaction can be described by an effective (Overhauser) magnetic field \mathbf{B}_n that acts on the electron spins and has been detected optically^{2,9} and in transport experiments.^{10,11} The restriction of electron-spin pumping to small quantum-confined regions allows one to study nuclear polarization in semiconductor heterostructures¹²⁻¹⁴ and quantum dots.^{10,11,15} All-electrical injection and detection of electron spins were recently dem-onstrated in bulk GaAs^{16,17} and Si,^{18,29} and it was suggested that the linewidth of Hanle peaks is influenced by dynamic nuclear polarization (DNP) at lower temperatures.¹⁹

Here, we investigate the consequences of DNP in an allelectrical nonlocal spin device consisting of Fe injection and detection contacts and a *n*-doped GaAs spin transport channel. From measurements of the nonlocal voltage U_{nl} at the detection contact, we obtain quantitative information on the Overhauser field B_n and on the nuclear-spin dynamics in the GaAs channel. By applying an external magnetic field **B** $=B_x \hat{x} + B_z \hat{z}$ [see definition of coordinate system and sample layout in Fig. 1(a)], we investigate the interdependence of nuclear- and electron-spin dynamics by (i) in-plane sweeps of B_z at constant B_z and by (ii) perpendicular (Hanle) sweeps of B_z at constant B_x . For (i), we probe the depolarization peak in U_{nl} at $B_x=0$, previously reported in Ref. 16, which we here explain in terms of a Hanle-type electron-spin dephasing arising from a perpendicular B_n . In (ii), we observe that apart from the Hanle peak at $B_z=0$, two satellite peaks occur at finite and opposite B_z values provided a finite B_x is oriented parallel to the spin-polarization vector of the injected electrons. We show that these satellite peaks occur when the average B_n cancels the external field, leading to a reduction in spin dephasing. A comparison of the measurements with a numerical model allows us to extract quantitative values for B_n , the sign of injected electron spins, and a lower limit for injected spin polarization. We find that majority spins are injected into GaAs and that minority spins get accumulated in GaAs when electrons are extracted from the semiconductor. A lower limit of 0.5% for the spin polarization in the GaAs channel is estimated at 25 K and a current of 30 μ A through a contact area of 360 μ m².



FIG. 1. (Color online) (a) Coordinate system with external magnetic field and spin vectors and a scheme of the nonlocal sample geometry and measurement setup with two central ferromagnetic injection (2) and detection (3) bars and two outer reference bars (1) and (4). (b) The nonlocal voltage U_{nl} exhibits jumps for both upward (black) and downward (dashed blue) sweeps of B_x . The jumps are related to magnetization switching of the injection and detection bars into parallel and antiparallel configurations. (c) The central peak in U_{nl} is a measure of nuclear polarization as is indicated in a sweep of B_x after waiting for 10 min at $B_x = -50$ mT and a time t at $B_x^{set} = 6.5$ mT [position IV in (b)]. The fitted height ΔU_0 of the peak vs t is shown in (d) for different waiting fields B_x^{set} labeled I–V in (b) and (d).

The spin devices were prepared by epitaxially growing a 1-µm-thick n-doped GaAs epilayer with Si doping concentration of 5×10^{16} cm⁻³ onto an undoped GaAs(001) wafer. The doping concentration within 15 nm below the surface is 6×10^{18} cm⁻³, followed by a gradual reduction to 5 $\times 10^{16}$ cm⁻³ within 15 nm. The highly doped surface region allows one to obtain a thin Schottky barrier for efficient charge-carrier injection.^{5,6} The substrates, protected by an As capping layer, are then transferred into an ultrahigh-vacuum chamber for Fe growth by thermal sublimation. Prior to deposition of a 4-6-nm-thick Fe film, the As capping was removed by heating the wafer to 400 °C for 1 h. The GaAs surface was inspected by scanning tunneling microscopy to have a $c4 \times 4$ reconstruction. A final 2–4-nm-thick Au layer protects the Fe film from oxidation. Samples were annealed in situ at 220 °C for 10 min before further processing. By means of optical or e-beam lithography and ion milling, the Fe layer was patterned into stripes that are 60 μ m long and 6 and 2 μ m wide (parallel to the [110] orientation of the GaAs substrate) serving as injection (2) and detection (3) contacts, as indicated in Fig. 1(a), which shows a scheme of a sample. Unless stated otherwise, the separation between injection and detection contacts was 3 μ m. A 100-nm-thick layer of Al₂O₃ isolates large Au/Ti bond pads for contacting the Fe bars from the substrate. Injection and detection of electron spins are achieved in the nonlocal geometry.^{16,20} A current I_{inj} is drawn from contact (1) to contact (2) such that spin is injected at contact (2) for $I_{inj} > 0$ and spin filtering occurs for $I_{inj} < 0$. The nonlocal voltage U_{nl} is measured between contact (3) and contact (4) using both dc and ac lock-in techniques. Both approaches yield equivalent results, and in the following we use a superscript to differentiate ac (I_{ini}^{ac}) from dc (I_{ini}) excitation of the injection current. Measurements were performed in two different cryostats with variable-temperature inserts and a superconducting magnet system. One of them allows application of magnetic fields B_x and B_{τ} along two independent axes.

Figure 1(b) shows the nonlocal voltage U_{nl} measured as a function of B_x at a temperature T=5 K for $I_{inj}^{ac}=1.6 \ \mu$ A. In an upward sweep of B_x , U_{nl} jumps to a higher value at $B_x \approx 5$ mT when the first bar reverses its magnetization, and drops back down at the reversal of the second bar, i.e., when the magnetizations are parallel again. In the following, we subtract an offset \overline{U}_{nl} from U_{nl} so that $U_{nl}=0$ lies exactly in the middle between the two jumps, marking the nonlocal voltage level with zero electron-spin polarization. In addition to the jumps, U_{nl} exhibits a peak at $B_x=0$ mT, indicative of a loss of average electron-spin polarization at contact (3). Its height ΔU_0 depends on the history before performing the B_x sweep and appears within a time scale of several minutes, which is characteristic of nuclear-spin-lattice relaxation times τ_1 .²¹

To demonstrate that the depolarization peak is related to nuclear-spin polarization, we performed a series of measurements in which DNP was built up and then reversed while monitoring ΔU_0 . The system is initialized at $B_x = -50$ mT for 10 min with $I_{inj} = -1.6 \ \mu$ A such that nuclear spins get dynamically polarized until they reach a steady-state value. Then B_x is swept to a value B_x^{set} . The nuclear spins adiabatically follow the external field and if B_x crosses zero reverse their direction in space.²² After waiting a time t at $B_x = B_x^{\text{set}}$, the depolarization peak is immediately recorded by sweeping B_x across $B_x=0$ mT with $I_{ini}^{ac}=1.6 \mu A$. This was repeated for several values of t to obtain data as shown in Fig. 1(c) for $B_x^{\text{set}} = 6.5 \text{ mT} [\text{corresponding to arrow IV in Fig. 1(b)}], where$ ΔU_0 first decreases, passes through a minimum at t ≈ 6 min and saturates again at t > 10 min. This time dependence of ΔU_0 is a strong indication that it is a measure of the nuclear polarization. Substantial nuclear-spin polarization $\langle I \rangle$ can be built up by hyperfine-induced flip-flop spin scattering if an average electron-spin polarization $\langle S \rangle$ is sustained, such as in our case by injection or filtering of spin-polarized electrons from the Fe contact (2). The effective Overhauser magnetic field $\mathbf{B}_n \propto \langle \mathbf{I} \rangle$, which in steady state can be described bv²

$$\mathbf{B}_n = f b_n \frac{\mathbf{B} \cdot \langle \mathbf{S} \rangle}{B^2} \mathbf{B}.$$
 (1)

Here, $f \leq 1$ is a leakage factor that takes into account the possibility of nuclear-spin relaxation by other channels than through a hyperfine-induced flip-flop process, and b_n =-8.5 T in GaAs.^{9,23} Equation (1) only holds for small $\langle S \rangle$ and neglects the Knight shift and the effect of dipole-dipole interaction between nuclear spins that is only important for typically B < 1 mT, where it leads to a drop of $\langle \mathbf{I} \rangle$ to zero at B=0. In Eq. (1), $\langle S \rangle$ can be replaced by $S_0 = S_0 \hat{x}$, which denotes the average spin polarization of the GaAs electron density without precession, see Fig. 1(a). Depending on the sign of $B_x S_0$, **B**_n is aligned parallel or antiparallel to **B**. When **B** reorients from $-\hat{\mathbf{x}}$ into the $\hat{\mathbf{x}}$ direction, the spatial direction of DNP does not change, which means that after adiabatic reversal of the nuclear polarization at $B_x=0$, the nuclear polarization will first decrease and then repolarize into the opposite direction. This is exactly what is observed in ΔU_0 . A similar decrease and subsequent increase in ΔU_0 are measured if the sign of I_{ini} is reversed, whereby electron spins with the opposite sign will accumulate below the injection contact (data not shown). In Fig. 1(d), ΔU_0 is plotted as a function of t for different B_x^{set} , labeled I to V in Fig. 1(b). For position (I) and (V), ΔU_0 does not fall to zero but slightly increases before saturation. Because B_r^{set} remains negative (I) or is positive and large enough such that the magnetization of both injection and detection contact reverses (V), no crossing of $\langle \mathbf{I} \rangle = 0$ is necessary to attain steady state. Only for the two intermediate fields (III and IV), where B_x has crossed zero but the magnetization of the injection contact has not yet reversed, will ΔU_0 drop to zero and reappear afterward. For $B_x^{\text{set}}=0$, build up of nuclear-spin polarization is prevented, see trace II in Fig. 1(d), because of inefficient DNP for $\mathbf{B} \cdot \langle \mathbf{S} \rangle = 0.$

To understand the reason for the occurrence of the depolarization peak in U_{nl} , we have carried out measurements of U_{nl} versus B_x for different B_z shown in Fig. 2. The nuclearspin polarization is initialized at $I_{inj}=20 \ \mu A$ and B_x = -50 mT for 15 min. B_x is then swept up and down with a sweep rate of 25 mT/min, for different B_z from -6 to 6 mT in steps of 0.5 mT. Figure 2(a) shows a trace measured at B_z



FIG. 2. (Color online) (a) U_{nl} as a function of B_x at a fixed B_z =-3 mT at 20 K. The red curve is a Lorentzian with a half width ΔB =-3 mT and a height ΔU_0 =4.2 μ V that has been adjusted for best fit to the depolarization peak at B_x =0. For antiparallel magnetization of the central contacts the Lorentzian is inverted and offset by the maximum spin signal ΔU_{nl} . (b) Peak width ΔB as a function of B_z . At vanishing B_z , ΔB saturates at a finite value ΔB_0 =0.8 mT. (c) ΔU_0 (squares) dips at B_z =0 mT because of the nuclear local dipolar field. The solid red line is calculated using a model as described in the text. (d) Measured values of ΔB around B_z =0 mT (squares), showing a local peak, and model (solid red line) as described in the text. (e) Temperature dependence of $\Delta U_0/\Delta U_{nl}$, which is slightly larger than 0.5 for low temperatures and vanishes for $T \ge 50$ K.

=-3 mT and T=20 K. ΔU_0 extends slightly beyond $\Delta U_{\rm nl}/2$, defined as half the separation between $U_{\rm nl}$ for parallel and antiparallel magnetization at large $B_{\rm x}$ where the influence of the depolarization peak can be neglected. The peak can be fitted by a Lorentz curve $\propto (1 + B_r^2 / \Delta B^2)^{-1}$, where the half width at half maximum ΔB of the peak follows $(B_z^2 + \Delta B_0^2)^{1/2}$ with $\Delta B_0 = 0.8$ mT, see Fig. 2(b). The Lorentz shape with a width that approximates B_z suggests that the depolarization peak is due to the rotation of the total magnetic field $\mathbf{B}_{tot} = \mathbf{B} + \mathbf{B}_n$ in the xz plane as B_x is swept through zero. For sufficiently large B_{tot} , the electron spins precess fast enough that $\langle S \rangle$ points along (or against) **B**_{tot}. U_{nl} is given by the projection of $\langle S \rangle$ onto $\hat{x},$ and thus becomes proportional to $B_x^2/(B_x^2+B_z^2)$,²⁴ i.e., follows a Lorentz curve with a half width equal to B_{z} , as observed in the experiment for larger $|B_{z}|$ [the solid red curve in Fig. 2(a) is a Lorentzian fit with $\Delta B = |B_z| = 3$ mT and ΔU_0 as the only free fit parameter].

Next we discuss the behavior of ΔB and ΔU_0 close to $B_z=0$. We have repeated measurements as the ones shown in Fig. 2(b) but with higher resolution around $B_z=0$ and at T=25 K. As shown in Fig. 2(c), a dip in ΔU_0 appears at $B_z=0$ mT with a full width at half maximum of about 0.5 mT and a decrease from 4.5 to 2 μ V. This is evidence of the presence of a small field component B_y along \hat{y} that orients \mathbf{B}_n into the y direction, accompanied by a partial depolarization of the nuclear spins because of dipole-dipole interaction between the nuclear spins. For a local dipole field B_L , $B_n = B_n^0 B^2 / (B^2 + B_L^2)$, where B_n^0 is the nuclear field for $B \ge B_L$. In GaAs, $B_L \approx 1$ mT.⁹ An expression for U_{nl} is obtained for arbitrary B_{tot} by separating $\langle \mathbf{S} \rangle$ into its components along and perpendicular to \mathbf{B}_{tot} . We find $U_{nl} = -\frac{\Delta U_{nl}}{2} [\cos^2 \alpha]$

 $+(\sin^2 \alpha)H(B_{tot})/H(0)]$, where $H(B_{tot})$ is the Hanle line shape as defined in Eq. (1) of Ref. 16 and α = $\arctan \sqrt{B_v^2 + B_z^2}/B_x$. The term proportional to $\cos^2 \alpha (\sin^2 \alpha)$ corresponds to the component of $\langle S \rangle$ parallel (perpendicular) to **B**_{tot}. ΔU_0 is given by the value of $U_{\rm nl}$ at $\alpha = 0$, $\frac{\Delta U_{\rm nl}}{2}$ $-H(B_{tot})/H(0)$], and therefore follows a typical Hanle curve as a function of B_{tot} : For $B \leq B_L$, ΔU_0 decreases because B_n depolarizes and thus B_{tot} decreases, making Hanle-type spin dephasing less efficient. For intermediate B_{tot} , $H(B_{tot})$ becomes negative and therefore $\Delta U_0 > \Delta U_{\rm nl}/2$. The solid line in Fig. 2(c) shows the calculated ΔU_0 using the model described above and reproducing the observed dip. As parameters, we used a diffusion constant $D=0.002 \text{ m}^2/\text{s}$, spin lifetime $\tau_s = 10$ ns, $B_n^0 = 47$ mT, $B_L = 1$ mT, and $B_v = 0.2$ mT. Interestingly, in this model, ΔB does not drop to zero, but even increases around $B_z=0$ mT. Figure 2(d) shows the measured ΔB having a local peak at $B_z=0$, as well as the results of the model using the same parameters as above (solid red line). In the model, the local increase in ΔB is because of a change in the form of the depolarization peak whose height ΔU_0 decreases while its tails remain unchanged because they are determined by the term proportional to $\cos^2 \alpha$. Compared to the model, the measured ΔB exhibits a more pronounced local peak at $B_z = 0$. We note that the sizes of ΔU_0 and ΔB at $B_z=0$ are determined by the interplay of many different mechanisms, from which our analytical model takes into account the electron-spin dynamics along the diffusive path between injection and detection contacts, a homogeneous Overhauser field aligned with the external field, a decrease in nuclear polarization at B=0 because of the local dipole field, and a finite magnetic field component along $\hat{\mathbf{y}}$. We have neglected the Knight shift that reorients the direction of the Overhauser field, as well as the possibility of electron-spin dephasing in a locally fluctuating Overhauser field, effects that both will affect the details of $U_{\rm nl}$ around B=0.

The temperature dependence of $\Delta U_0 / \Delta U_{nl}$ at $|B_z| < 1$ mT is shown in Fig. 2(e). For T < 20 K, $\Delta U_0 / \Delta U_{nl}$ remains slightly above 0.5, indicative of the intermediate field regime. At $T \ge 25$ K, $\Delta U_0 / \Delta U_{nl}$ decreases. Within the explanation given above, B_{tot} must therefore be of the same order as the Hanle peak width, i.e., about 3 mT. From measurements of satellite peaks in Hanle configurations (explained later), we can determine B_n and extrapolate values well above 20 mT for 25 K and initialization at $B_x = -50$ mT, which is much larger than 3 mT, thus supporting the idea that the nuclear dipolar mechanism reduces B_n . Above T=50 K, where DNP becomes inefficient, ΔU_0 is no longer observable.

As mentioned in Ref. 19, nuclear-spin polarization also modifies the line shape of the Hanle curve U_{nl} versus B_z . An even more profound effect occurs when B_n points against Band is so large that the two fields cancel. In such a situation, Hanle-type spin dephasing is strongly reduced, leading to two satellite peaks in U_{nl} at finite and opposite B_z values. Figure 3(a) shows such measurements at fixed $B_x=2.5$ mT (solid lines) and -2.5 mT (dashed lines), and for the magnetization of the detection contact oriented parallel (black) and antiparallel (gray or red) to that of the injection contact.



FIG. 3. (Color online) (a) Hanle measurements of U_{nl} versus B_z for fixed $B_x = \pm 2.5$ mT and parallel (antiparallel) magnetization of the central contact bars indicated by black (gray or red) arrows. B_z was swept at a rate of 40 mT/min. (b) Maximum spin signal ΔU_{nl} as a function of I_{inj} . For spin injection, i.e., $I_{inj} > 0$, the spin signal goes through a maximum with increasing I_{inj} that correlates with the satellite peak position in the Hanle measurement in (c) as a function of B_z and I_{inj} . For spin filtering, i.e., $I_{inj} < 0$, no satellite peaks appear because the nuclear field B_n is parallel to the externally applied field. Data in (a) and (c) were averaged over an up and down sweep of B_z .

The magnetization of the latter is oriented along positive B_x . All data in Fig. 3 were obtained on a sample with injection and detection contacts separated by 5 µm. According to Eq. (1), B_n points against or along B, depending on the sign of B_xS_0 . The appearance of the satellite peaks requires that $B_xS_0>0$. For $I_{inj}>0$, we observe the satellite peaks at B_x <0 and for $I_{inj}<0$ at $B_x>0$ [see Fig. 4(a)]. Therefore, S_0 is negative (and antialigned with the magnetization **M** of the injection contact) in the case of spin injection and positive (aligned with **M**) for spin filtering. In agreement with previous observations,^{25,16} this means that majority spins are injected from Fe into GaAs.

The position of the satellite peaks is a direct measure of the nuclear field because there $\mathbf{B} = -\mathbf{B}_n$. The sign and magnitude of S_0 can be controlled with the injection current I_{inj} . As shown in Fig. 3(b), ΔU_{nl} reverses its sign at $I_{inj}=0$. For $I_{\rm inj} > 0$, $\Delta U_{\rm nl}$ is positive and reaches a peak at $I_{\rm inj} = 45 \ \mu A$, whereas for negative I_{ini} it saturates at a negative value. The separation of the satellite Hanle peaks measured at B_x =-1.6 mT and shown in Fig. 3(c) follows the same behavior as $\Delta U_{\rm nl}$, indicating that the nuclear field monotonically depends on S_0 . This is also evidence that the peak in ΔU_{nl} for $I_{\rm ini} > 0$ directly reflects a maximum spin polarization in the GaAs channel and is not due to a dependence of the detector sensitivity on the injection current. In Fig. 3(c), no satellites are observed for $I_{ini} < 0$ because of the opposite direction of S_0 . Similarly, the appearance of the satellites can be controlled by the orientation of the magnetization of the injection contact (data not shown).

Figure 4(a) shows a color scale plot of measured U_{nl} as a function of B_x and B_z . For small B_x , we observe a linear dependence of the satellite peak separation on B_x . From the



FIG. 4. (Color online) (a) U_{nl} versus B_z for different B_x , measured at I_{ini} =-30 μ A and T=25 K. Magnetizations were set parallel along the positive x direction. For each value of B_x , B_z was swept at 50 mT/min between ± 40 mT. (b) Calculated spin polarization $\langle S_{v} \rangle$ at detection contact using Monte Carlo simulation. D =0.002 m² s⁻¹, τ_s =10 ns, $b_n f S_0$ =45 mT in (b)–(e). The dashed black lines indicate expected peak positions for a saturated B_n according to Eq. (1). (c) Map of $\langle S_x \rangle$ versus y and B_z for B_x =2.5 mT. Spin is injected at y < 0, and data in (b) are averaged at the detection contact located at $3 < y < 5 \ \mu m$. (d) B and B_n versus B_z for $B_x=2.5$ mT. B_n was calculated for steady-state condition (black) and for $r\tilde{\tau}_1$ =250 mT averaged at the detection contact (dotted red line) and in between the contacts (dashed red line). Dots indicate positions where $B = -B_n$ and satellite peaks are expected. (e) Hysteresis and broadening of satellite peaks in calculated $\langle S_x \rangle$ at detection contact for locally varying B_n [dashed red line, same parameters as in (d)] and uniform/saturated B_n .

condition $\mathbf{B} + \mathbf{B}_n = 0$ and Eq. (1), i.e., when assuming that B_n is at its steady-state value for all measured B, the satellite peak positions are given by

$$B_{z} = \pm \sqrt{B_{x}(-fb_{n}S_{0} - B_{x})}.$$
 (2)

As $-fb_nS_0 \gg B_x$ for our measurements, we expect a quadratic dependence, $B_x \propto B_z^2$, at the satellite peaks. In an optical orientation measurement with oblique magnetic field, similar satellite peaks were observed in the circular polarization of photoluminescence as a function of B_z .²⁶ Also there, a linear increase in the satellite peak separation with B_r was observed, which was interpreted as a B-dependent leakage factor f. As we will demonstrate with a numerical simulation, our data can be explained without assuming a field dependent f, but taking into account the long τ_1 of nuclear spins whose polarization does not reach steady-state at individual field values within a sweep of B_{z} . We performed the numerical simulation of the diffusing electron spins using a Monte Carlo approach by assigning one-dimensional spatial coordinates y_i , velocities v_i , and three-dimensional spin directions \mathbf{s}_i to electrons labeled i=1 to *n*. At constant time intervals δt , y_i are updated to $y_i + v_i \delta t$, and to a fraction of the *n* electrons a new random velocity is assigned, thus simulating the diffusive scattering process characterized by the diffusion constant D. The new velocity v_i is distributed between $-v_F$ and v_F according to the projection of a two-dimensional vector of length v_F onto the y axis. Spin coordinates s_i are regularly updated by calculating the rotation about the locally varying $\mathbf{B} + \mathbf{B}_n$ and by accounting for a spin decay at rate $1/\tau_s$. At a constant rate, spin-polarized electrons are injected by assigning coordinates y_i within the injection contact area (-6 to 0 μ m) to new electrons *i*. A similar method but without including hyperfine interaction was used in Ref. 27. We let B_n locally evolve with a time constant τ_1 toward the steady-state nuclear field as calculated by Eq. (1), thus accounting for the fact that typical sweep rates *r* in the experiment are faster than $1/\tau_1$. We neglect nuclear-spin diffusion because of the small diffusion constant (10^3 Å/s has been measured in Ref. 28). The simulation is run for a time $5\tau_s$, ensuring a converging self-consistent solution.

The nonlocal voltage U_{nl} is proportional to the electronspin component $\langle S_x \rangle$ averaged over the detector contact at $3 < y < 5 \mu m$, and is plotted in Fig. 4(b) as a function of B_x and B_z . In Fig. 4(c), a map of $\langle S_x \rangle$ versus y and B_z is shown for $B_x=2.5$ mT. In the simulation, $\tau_s=10$ ns, D=2 $\times 10^{-3}$ m²/s, and $r\tau_1 = 250$ mT are used. We obtain an excellent match with the experimental data in Fig. 4(a) with $fb_n S_0 = 45$ mT, where S_0 is the averaged x component of $\langle S \rangle$ for $0 \le y \le 3$ µm and at $B_z = 0$. The solid line in Fig. 4(b) indicates the increase with $\sqrt{B_x}$ of the satellite peak separation described by Eq. (2) that is expected when B_n reaches its steady-state value for all field positions. In contrast to this, the simulation reproduces the experimentally observed linear increase for small B_x . In Fig. 4(d), calculated B_n is shown versus B_{τ} averaged in between the two contacts (dashed red line) and below the detection contact (dotted red line). Because $r\tau_1$ is much larger than the sweep range of ± 40 mT, B_n does not follow the steady-state value as B_7 is swept (shown as solid black line), but is rather uniform at B_n $\approx -fb_n S_0 B_x \langle \frac{1}{R} \rangle$, where $\langle \frac{1}{R} \rangle$ is the time average of $\frac{1}{R}$ for a sweep of B_z and S_0 is averaged in between the contacts or below the detection contact, respectively. From this, a splitting that is linear in B_r directly follows. Note that with the fast sweep rates that we are measuring at, the history before a single field sweep affects the size of B_n . In order to suppress this effect, we have swept B_z up and down three times for each value of B_x and plot the average of the last up and down sweeps in Fig. 4(a). Within measurement accuracy, the data does not change if further up and down sweeps are performed. The averaging of up and down sweeps removes a small asymmetry of the satellite peak positions with $\pm B_z$ of individual measured up and down sweeps (not shown), in which the positions for up and down sweeps differ by less than 2 mT, comparable to the calculated curve shown in Fig. 4(e). We expect that the main error in the determination of fb_nS_0 stems from the uncertainty in B_n introduced by the fast sweep rate and is on the order of about 10%. If we ignore the linear increase in peak separation with B_x that is indicative of a fast sweep rate, we obtain an overestimated value for fb_nS_0 of 68 mT from the steady-state analytical model of Eq. (2) using the satellite peak positions of $B_z \approx \pm 16$ mT at B_x =4 mT.

From the data in Fig. 4(d) one sees that B_n depends on y.

Therefore $\mathbf{B} = -\mathbf{B}_n$ is not fulfilled over the entire distance between injection and detection contacts, leading to a reduced height of the satellite peaks. In Fig. 4(e), the dashed red line is a linecut through the data in Fig. 4(b) at B_x =2.5 mT, whereas for the data of the solid black line, B_n is uniformly fixed to the steady-state value predicted by Eq. (1) with $fb_nS_0=45$ mT. In the latter case, the satellite peaks reach the full height because at $\mathbf{B}=-\mathbf{B}_n$, the total field disappears everywhere in the sample. The decrease in the satellite peak height is significantly underestimated in the simulation, compare with Fig. 3(a). This indicates that B_n might even be more inhomogeneous in the sample than predicted by the Monte Carlo simulation.

The measured size of $fb_nS_0=45$ mT allows a lower estimate of the injected spin polarization. The value b_n =-8.5 T known from literature (Ref. 9) limits S_0 to about 0.5% for f=1. To obtain a rough estimate of the polarization of the injected current from this, we have to account for the ratio of injected electrons to the 5×10^{16} cm⁻³ electrons that are already in the sample. Within a spin lifetime τ_s , $I_{inj}\tau_s/e$ = 1.3×10^6 electrons are injected and diffused into a volume $60 \ \mu m \times [6 \ \mu m + \sqrt{(D\tau_s)}] \times 1 \ \mu m$, corresponding to a density of 2.1×10^{15} cm⁻³, i.e., the injected spins make up about 1/24 of the electron density. Accordingly, the spin polarization of injected electrons is at least 10% for f=1, I_{inj} =-30 μA , and T=25 K.

In conclusion, we have found that the nonlocal voltage $U_{\rm nl}$ in an all-electrical spin injection and detection device exhibits distinct signatures of dynamically polarized nuclear spins that can be used to measure the Overhauser effective magnetic field B_n and to study nuclear-spin dynamics. We obtained a quantitative understanding of the depolarization peak in in-plane magnetic field sweeps. Because the peak height sensitively depends on small stray fields on the order of 0.1 mT and because of nuclear dipole-dipole interaction, a quantitative relation between the shape/size of the peak and B_n is difficult to obtain. However, a quantitative measurement of a spatially averaged B_n is achieved by observing the satellite peaks that occur in a Hanle measurement when B $+\mathbf{B}_n=0$. By comparison with a self-consistent simulation of spin diffusion and hyperfine interaction, we obtain a value for fb_nS_0 of 45 mT at 25 K and $I_{inj}=-30 \mu A$, from which the sign of injected spin polarization can be determined and its magnitude estimated. We can explain our data using a leakage factor f that does not depend on the external magnetic field. The observed nuclear-spin signatures enable the study of nuclear-spin dynamics including nuclear-spin resonance in small semiconductor/ferromagnet structures by a transport measurement. Of specific interest is to extend this method to investigate hyperfine interaction in other semiconductor materials such as silicon²⁹ or graphene³⁰ where the spins cannot be accessed easily optically.

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